

Vishay Semiconductors

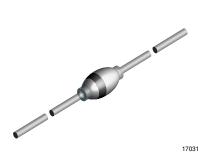
Standard Sinterglass Diode

Features

- High temperature metallurgically bonded constructed rectifiers
- · Cavity-free glass passivated junction
- Hermetically sealed package
- 2.0 ampere operation at T_{amb} = 75 °C with no thermal runaway

Mechanical Data

Case: DO-204AP Sintered glass case



| Terminals: Solder plated axial leads, solderable per | Mounting Position: Any |
|--|------------------------|
| MIL-STD-750, Method 2026 | Weight: approx. 560 mg |
| Polarity: Color band denotes cathode end | |

Parts Table

| Part | Type differentiation | Package |
|------|---------------------------|---------------|
| G2A | V _{RRM} = 50 V | DO-204AP(G-1) |
| G2B | V _{RRM} = 100 V | DO-204AP(G-1) |
| G2D | V _{RRM} = 200 V | DO-204AP(G-1) |
| G2G | V _{RRM} = 400 V | DO-204AP(G-1) |
| G2J | V _{RRM} = 600 V | DO-204AP(G-1) |
| G2K | V _{RRM} = 800 V | DO-204AP(G-1) |
| G2M | V _{RRM} = 1000 V | DO-204AP(G-1) |

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

| Parameter | Test condition | Part | Symbol | Value | Unit |
|--|--|------|--------------------|-------|------|
| Reverse voltage = Repetitive peak reverse voltage | see electrical characteristics | G2A | $V_{R} = V_{RRM}$ | 50 | V |
| | | G2B | $V_{R} = V_{RRM}$ | 100 | V |
| | | G2D | $V_{R} = V_{RRM}$ | 200 | V |
| | | G2G | $V_{R} = V_{RRM}$ | 400 | V |
| | | G2J | $V_{R} = V_{RRM}$ | 600 | V |
| | | G2K | $V_{R} = V_{RRM}$ | 800 | V |
| | | G2M | $V_{R} = V_{RRM}$ | 1000 | V |
| Maximum average forward rectified current | 0.375 " (9.5 mm) lead length at $T_{amb} = 75 \ ^{\circ}C$ | | I _{F(AV)} | 2.0 | A |

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| Parameter | Test condition | Part | Symbol | Value | Unit |
|--|--|------|-----------------------------------|---------------|------|
| Peak forward surge current | 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method) | | I _{FSM} | 50 | A |
| Maximum full load reverse current | full cycle average 0.375 " (9.5 mm) lead length at $T_{amb} = 100 \ ^{\circ}C$ | | I _{R(AV)} | 100 | μΑ |
| Operating junction and storage temperature range | | | T _J , T _{STG} | - 55 to + 175 | °C |

Maximum Thermal Resistance

 T_{amb} = 25 °C, unless otherwise specified

| Parameter | Test condition | Symbol | Value | Unit | |
|-------------------------------|----------------|------------------|-------|------|--|
| Typical thermal resistance 1) | | R _{θJA} | 55 | K/W | |

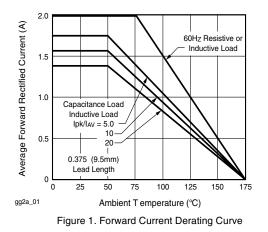
¹⁾ Thermal resistance from junction to ambient at 0.375 " (9.5 mm) lead length, P.C.B. mounted

Electrical Characteristics

 $T_{amb} = 25$ °C, unless otherwise specified

| Parameter | Test condition | Part | Symbol | Min | Тур. | Max | Unit |
|--|---|------|-----------------|-----|------|-----|------|
| Maximum instantaneous forward voltage | I _F = 2 A | G2A | V _F | | | 1.2 | V |
| | | G2B | V _F | | | 1.2 | V |
| | | G2D | V _F | | | 1.1 | V |
| | | G2G | V _F | | | 1.1 | V |
| | | G2J | V _F | | | 1.1 | V |
| | | G2K | V _F | | | 1.1 | V |
| | | G2M | V _F | | | 1.1 | V |
| Maximum reverse current | $V_{R} = V_{RRM}, T_{amb} = 25 \ ^{\circ}C$ | | I _R | | | 1.0 | μΑ |
| | $V_{R} = V_{RRM}, T_{amb} = 150 \text{ °C}$ | | I _R | | | 100 | μΑ |
| Typical reverse recovery time | $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$ | | t _{rr} | | 1.5 | | μs |
| Typical junction capacitance | V _R = 4.0 V, f = 1 MHz | | Cj | | 15 | | pF |

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)



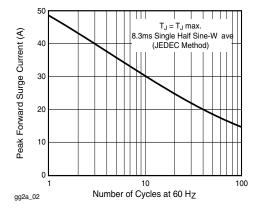


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

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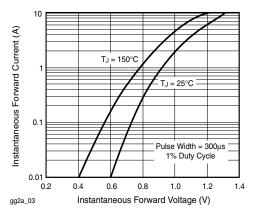
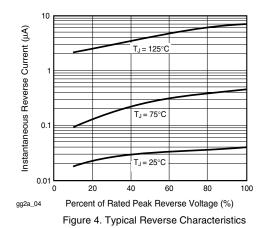
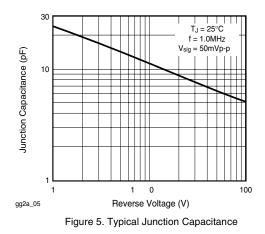


Figure 3. Typical Instantaneous Forward Characteristics





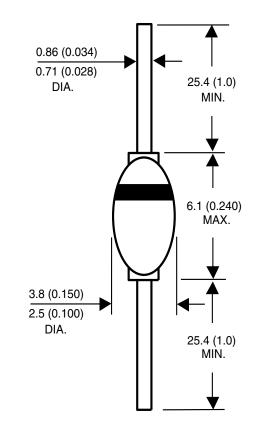
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G2A/B/D/G/J/K/M

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17030

Package Dimensions in mm (Inches)







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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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